



# HERAF801G THRU HERAF808G

Isolation 8.0 AMPS. Glass Passivated High Efficient Rectifiers



Voltage Range  
50 to 1000 Volts  
Current  
8.0 Amperes

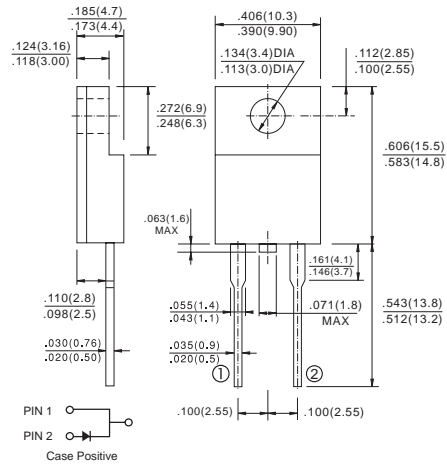
## Features

- ✧ Low forward voltage drop
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability

## Mechanical Data

- ✧ Cases: ITO-220AC molded plastic
- ✧ Epoxy: UL 94V-O rate flame retardant
- ✧ Terminals: Leads solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C/ 0.25" (6.35mm) from case for 10 seconds
- ✧ Mounting torque: 5 in – 1bs. Max.
- ✧ Weight: 2.24 grams

## ITO-220AC



Dimensions in inches and (millimeters)

## Maximum Rating and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	HERAF 801G	HERAF 802G	HERAF 803G	HERAF 804G	HERAF 805G	HERAF 806G	HERAF 807G	HERAF 808G	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length @ $T_C = 100^\circ C$	$I_{(AV)}$	8.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	150								A
Maximum Instantaneous Forward Voltage @ 8.0A	$V_F$	1.0		1.3		1.7				V
Maximum DC Reverse Current @ $T_A = 25^\circ C$ at Rated DC Blocking Voltage @ $T_A = 125^\circ C$	$I_R$	10.0 400								$\mu A$ $\mu A$
Maximum Reverse Recovery Time (Note 1)	$T_{rr}$	50				80				nS
Typical Junction Capacitance (Note 2)	$C_j$	80				60				pF
Typical Thermal Resistance (Note 3)	$R_{\theta_{JC}}$	2.0								$^\circ C/W$
Operating Temperature Range	$T_J$	-65 to +150								$^\circ C$
Storage Temperature Range	$T_{STG}$	-65 to +150								$^\circ C$

Notes: 1. Reverse Recovery Test Conditions:  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$   
 2. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.  
 3. Mounted on Heatsink Size of 2 in x 3 in x 0.25 in Al-Plate..

## RATINGS AND CHARACTERISTIC CURVES (HERAF801G THRU HERAF808G)

FIG. 1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

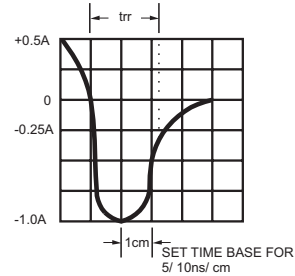
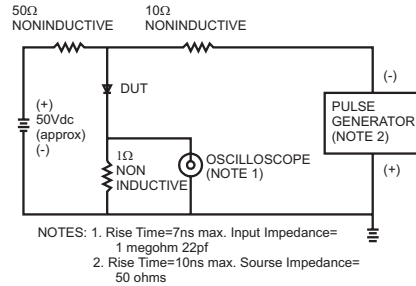


FIG. 2- MAXIMUM FORWARD CURRENT DERATING CURVE

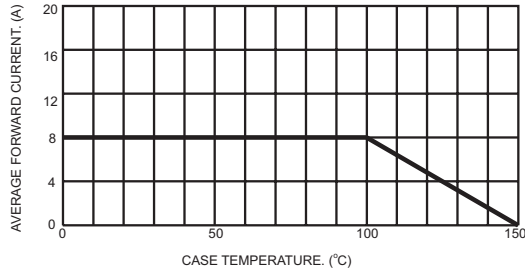


FIG. 3- TYPICAL REVERSE CHARACTERISTICS

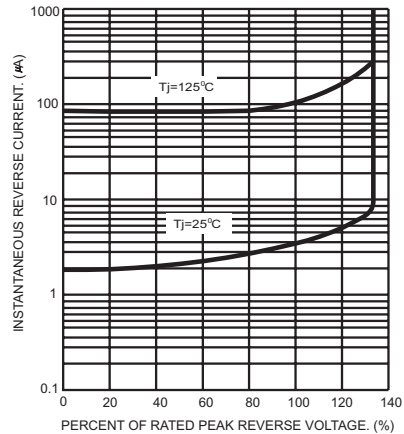


FIG. 4- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

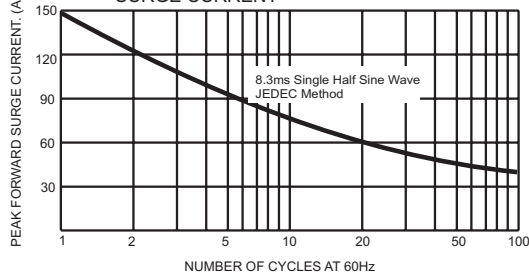


FIG. 6- TYPICAL FORWARD CHARACTERISTICS

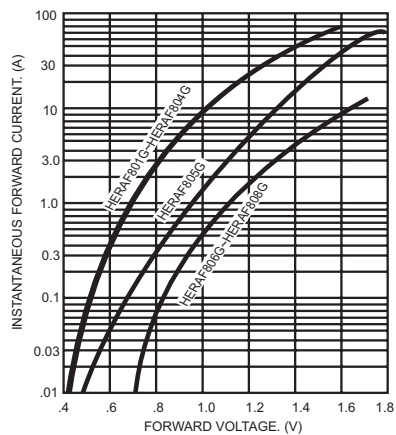


FIG. 5- TYPICAL JUNCTION CAPACITANCE

